

T495D336M025ATE100

T495, Tantalum, MnO2 Tantalum, 33 uF, 20%, 25 VDC, SMD, MnO2, Molded, Low ESR, 100 mOhms, 7343, Height Max = 3.1mm

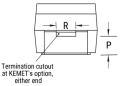
CATHODE (-) END VIEW



ANODE (+) END VIEW



SIDE VIEW



Click here for the 3D model.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
А	3.6mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	0.9mm REF
R	1mm REF
Х	0.1mm +/-0.1mm

Т

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Information	
Series	T495
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	446.84 mg
Shelf Life	156 Weeks
MSL	1

Specifications	
Capacitance	33 uF
Capacitance Tolerance	20%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
Resistance	100 mOhms (100kHz 25C)
Ripple Current	1225 mA (rms, 100kHz 25C), 1102.5 mA (rms, 85C), 490 mA (rms, 125C)
Leakage Current	8.3 uA (5min 25°C)

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